Electronic Supplementary Information

Solvothermal synthesis of GO/V2O⁵ composite as cathode material for rechargeable magnesium batteries

Xinchuan Du,^{ac} Gang Huang^{ac}, Yuling Qin^{ac} and Limin Wang^{ab*}

^a State Key Laboratory of Rare Earth Resource Utilization, Changchun Institute of Applied Chemistry, Chinese Academy of Sciences, Changchun 130022, Jilin, China E-mail: lmwang@ciac.ac.cn; Fax: +86 431 85262836; Tel: +86 431 85262447 ^b Changzhou Institute of Energy Storage Materials & Devices,

Changzhou 213000, Jiangsu, China

^c University of the Chinese Academy of Sciences, Beijing 100049, China

Experimental

Synthesis of GO/V₂O₅ composites. The GO/V₂O₅ composites synthetic route is illustrated in Fig. 1. 10 mg of graphene oxides (GO), which was freeze-dried for 24h, was dispersed in 35 mL of isopropanol (IPA) by ultrasonication for 2h, followed by addition of 200 μ L of vanadium oxytriisopropoxide (VOT) to form a homogeneous solution. Finally, all the mixture solution was transferred into a 50 mL Teflon-lined stainlesssteel autoclave, sealed and heated in an oven at 200 \degree C for 12h. The precipitate was collected by centrifugation, washed thoroughly with isopropanol (IPA) and deionized water several times. Ultimately, GO/V_2O_5 composites were obtained from a calcinating process at 800 \degree C in Ar.

Synthesis of electrolyte. The electrolyte solution of rechargeable Mg batteries comprises THF and a 0.25 M complex electrolyte of the Mg(AlCl₂BuEt)₂ formal stoichiometry, which was prepared by reacting $MgBu₂$ and $A|Cl₂Et$ at a ratio of 1:2 in THF solution.¹

Synthesis of GO. Using an improved method of Hummers' method to prepare graphitic oxide $(GO)^{2,3}$ the product was freeze-dried to reserve.

Calculation of the specific capacity.

Based on the equation mentioned in the paper:

 $xMg + V_2O_5 \leftrightarrow Mg_xV_2O_5$ (1)

The theoretical specific capacity (C_0) :

 C_0

$$
C_0 = \frac{N_A \times e \times z \times m}{t \times M_W}
$$
 (2)

The specific capacity of GO/V_2O_5 composite (when the $x = 0.66$, the most hosts 4):

$$
= \frac{6.02 \times 10^{23} \, mol^{-1} \times 1.6 \times 10^{-1}}{3600 \, s \times h^{-1} \times 182 \, g}
$$

Then as-prepared GO/V_2O_5 composite as cathode material for rechargeable Mg batteries could host how much (*y*) Mg ions per formula unit.

$$
y = \frac{178 \text{ mA} h/g}{194 \text{ mA} h/g} \times 0.66 = 0.60
$$

Figure S1. Schematic illustration of experimental battery.

Figure S2. The X-ray diffraction (XRD) pattern of as-synthesized precursors of GO/V_2O_5 composites.

Figure S3. XRD patterns of GO/V₂O₅ composites calcined at 400 °C (a)

and 600 ^oC **(b)**.

Figure S4. SEM images of GO/V₂O₅ composites calcined at 400 °C (a)

(b) and 600 ^oC **(c) (d)**.

Figure S5. TG curve of GO/V_2O_5 composites followed the heat treatment

process from R.T. to 800 °C at a heating rate of 10 °C min⁻¹.

Figure S6. SEM images of V_2O_5 prepared without GO.

Figure S7. Electrochemical properties of V_2O_5 prepared without GO.

Figure S8. Electrochemical impedance spectra for the samples of V_2O_5 and GO/V_2O_5 electrodes.

Figure S9. Cycling performance of GO/V_2O_5 electrodes at different rates.

Table S1. Cycling performance of GO/V₂O₅ composites and previously

Figure S10. Raman spectra of GO in GO/V₂O₅ composites calcined at

800 °C.

Figure S11. SEM images of (a) Mg anode and (b) $GO/V₂O₅$ composite

cathode after 20th.

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